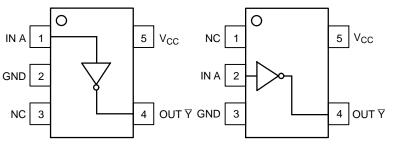
Single Inverter

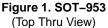
The NL17SG04 MiniGate[™] is an advanced high–speed CMOS Inverter in ultra–small footprint.

The NL17SG04 input structures provides protection when voltages up to 4.6 V are applied.

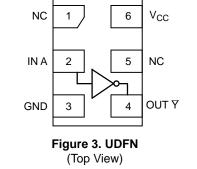
Features

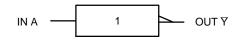
- Wide Operating V_{CC} Range: 0.9 V to 3.6 V
- High Speed: $t_{PD} = 2.3$ ns (Typ) at $V_{CC} = 3.0$ V, $C_L = 15$ pF
- Low Power Dissipation: $I_{CC} = 0.5 \ \mu A \ (Max)$ at $T_A = 25^{\circ}C$
- 4.6 V Overvoltage Tolerant (OVT) Input Pins
- Ultra-Small Packages
- These are Pb-Free and Halide-Free Devices











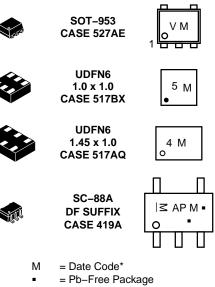




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MARKING DIAGRAMS



(Note: Microdot may be in either location) *Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT					
	SOT-953	SC-88A	UDFN6		
1	IN A	NC	NC		
2	GND	IN A	IN A		
3	NC	GND	GND		
4	OUT Y	OUT Y	OUT Y		
5	V _{CC}	V _{CC}	NC		
6			V _{CC}		

FUNCTION TABLE

A Input	Y Output
L	Н
Н	L

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

MAXIMUM RATINGS

Symbol	Para	meter	Value	Unit
V _{CC}	DC Supply Voltage		–0.5 to +5.5	V
V _{IN}	DC Input Voltage		-0.5 to +4.6	V
V _{OUT}	DC Output Voltage	Output at High or Low State Power–Down Mode ($V_{CC} = 0 V$)	-0.5 to V _{CC} +0.5 -0.5 to +4.6	V
I _{IK}	DC Input Diode Current	V _{IN} < GND	-20	mA
I _{OK}	DC Output Diode Current	V _{OUT} < GND	-20	mA
I _{OUT}	DC Output Source/Sink Current		±20	mA
I _{CC}	DC Supply Current per Supply Pin		±20	mA
I _{GND}	DC Ground Current per Ground Pin		±20	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10) Seconds	260	°C
TJ	Junction Temperature Under Bias		+150	°C
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3)	>2000 >100	V
ILATCHUP	Latchup Performance At	bove V_{CC} and Below GND at 125°C (Note 4)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
Tested to EIA/JESD22-A114-A.
Tested to EIA/JESD22-A115-A.

4. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics	Min	Max	Unit
V _{CC}	Positive DC Supply Voltage	0.9	3.6	V
V _{IN}	Digital Input Voltage	0.0	3.6	V
V _{OUT}	Output Voltage Output at High or Low State Power–Down Mode (V _{CC} = 0 V	e 0.0) 0.0	V _{CC} 3.6	V
T _A	Operating Temperature Range	-55	+125	°C
Δt / ΔV	Input Transition Rise or Fail Rate $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	′ 0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

					T _A =	25°C	T _A -55°C to	= +125°C		
Symbol	Parameter	Conditions		V _{CC} (V)	Min	Max	Min	Max	Unit	
V _{IH}	High-Level Input			0.9	V _{CC}		V _{CC}		V	
	Voltage			1.1 to 1.3	0.7xV _{CC}		0.7xV _{CC}		1	
				1.4 to 1.6	0.65xV _{CC}		$0.65 \mathrm{xV}_{\mathrm{CC}}$		1	
				1.65 to 1.95	$0.65 \mathrm{xV}_{\mathrm{CC}}$		$0.65 \mathrm{xV}_{\mathrm{CC}}$		1	
				2.3 to 2.7	1.7		1.7		1	
				3.0 to 3.6	2.0		2.0			
VIL	Low-Level Input			0.9		GND		GND	V	
	Voltage			1.1 to 1.3		0.3xV _{CC}		0.3xV _{CC}	1	
				1.4 to 1.6		0.35xV _{CC}		0.35xV _{CC}	1	
				1.65 to 1.95		0.35xV _{CC}		0.35xV _{CC}	1	
				2.3 to 2.7		0.7		0.7	1	
				3.0 to 3.6		0.8		0.8	1	
V _{OH}	High-Level V _{IN} = Output Voltage V _{IH} o V _{IL}		V _{IN} =	$I_{OH} = -20 \ \mu A$	0.9	0.75		0.75		V
		V _{IH} or V _{IL}	I _{OH} = -0.3 mA	1.1 to 1.3	0.75xV _{CC}		$0.75 \mathrm{xV}_{\mathrm{CC}}$		1	
			I _{OH} = -1.7 mA	1.4 to 1.6	0.75xV _{CC}		$0.75 \mathrm{xV}_{\mathrm{CC}}$		1	
			I _{OH} = -3.0 mA	1.65 to 1.95	Vcc-0.45		V _{CC} -0.4 5			
			I _{OH} = -4.0 mA	2.3 to 2.7	2.0		2.0			
			I _{OH} = -8.0 mA	3.0 to 3.6	2.48		2.48		1	
V _{OL}	Low-Level	V _{IN} =	I _{OL} = 20 μA	0.9		0.1		0.1	V	
	Output Voltage	V _{IH} or V _{IL}	I _{OL} = 0.3 mA	1.1 to 1.3		0.25xV _{CC}		0.25xV _{CC}		
			I _{OL} = 1.7 mA	1.4 to 1.6		0.25xV _{CC}		0.25xV _{CC}		
		I _{OL} = 3	I _{OL} = 3.0 mA	1.65 to 1.95		0.45		0.45	1	
			I _{OL} = 4.0 mA	2.3 to 2.7		0.4		0.4	1	
			I _{OL} = 8.0 mA	3.0 to 3.6		0.4		0.4	1	
I _{IN}	Input Leakage Current	0 ≤	$V_{IN} \le 3.6 V$	0 to 3.6		±0.1		±1.0	μΑ	
I _{CC}	Quiescent Supply Current	V _{IN} =	V _{CC} or GND	3.6		0.5		10.0	μΑ	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

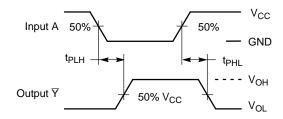
NL17SG04

Symbol	Parameter	Test Condition	V _{CC} (V)		T _A = 25° C	;	T _A -55°C to																	
				Min	Тур	Max	Min	Max	Unit															
t _{PLH} ,		$C_{L} = 10 \text{ pF},$	0.9	-	10.0	13.3	-	17.0	ns															
t _{PHL}	A to Y	$R_L = 1 M\Omega$	1.1 to 1.3	-	8.7	11.2	-	14.0																
			1.4 to 1.6	-	4.9	8.5	-	10.0																
				1.65 to 1.95	-	3.8	6.2	-	6.7															
		C _L = 15 pF, R _L = 1 MΩ	2.3 to 2.7	-	2.6	3.9	-	4.4																
			3.0 to 3.6	-	2.1	3.1	-	3.7																
			0.9	-	11.55	13.7	-	19.7	ns															
			1.1 to 1.3	-	7.2	10.8	-	15.6																
			1.4 to 1.6	-	5.4	9.3	-	11.2																
					1.65 to 1.95	-	4.2	6.9	-	7.1														
						l			2.3 to 2.7	-	2.8	4.4	-	5.0										
			3.0 to 3.6	-	2.3	3.4	-	3.9																
		$C_{L} = 30 \text{ pF},$	0.9	-	16.85	18.9	-	22.3	ns															
		R _L = 1 ΜΩ	1.1 to 1.3	-	10.2	13.4	-	17.5																
			1.4 to 1.6	-	7.4	13.1	-	15.9																
							l											1.65 to 1.95	-	5.6	9.2	-	9.6	
			2.3 to 2.7	-	3.7	5.7	-	6.1																
			3.0 to 3.6	-	2.9	4.4	-	4.8	1															
C _{IN}	Input Capacitance		0 to 3.6		3	-	-	-	pF															
C _{PD}	Power Dissipation Capacitance (Note 5)	f = 10 MHz	0.9 to 3.6	-	4	-	-	-	pF															

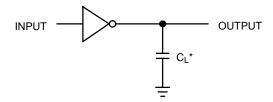
AC ELECTRICAL CHARACTERISTICS Input $t_f = t_f = 3.0$ ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

NL17SG04







*Includes all probe and jig capacitance. A 1–MHz square input wave is recommended for propagation delay tests.

Figure 6. Test Circuit

ORDERING INFORMATION

Device	Package	Shipping [†]
NL17SG04P5T5G	SOT-953 (Pb-Free)	8000 / Tape & Reel
NL17SG04DFT2G	SC–88A (Pb–Free)	3000 / Tape & Reel
NL17SG04AMUTCG	UDFN6 1.45x1 mm (Pb–Free)	3000 / Tape & Reel
NL17SG04CMUTCG	UDFN6 1x1 mm (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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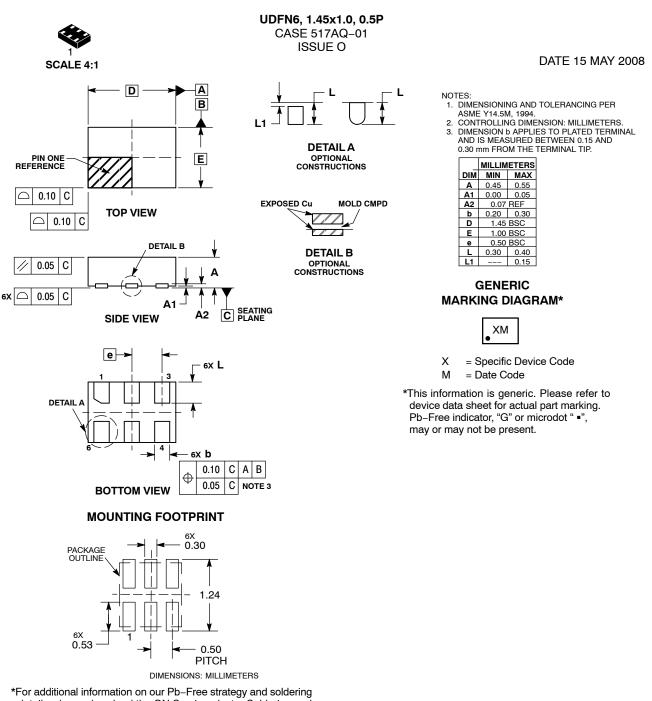




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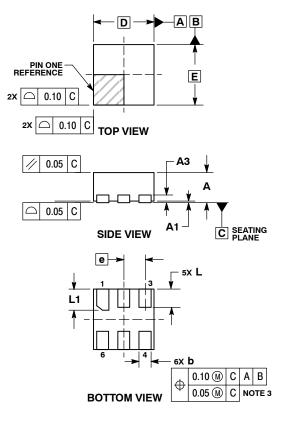
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NOTES:

UDFN6, 1x1, 0.35P CASE 517BX-01 ISSUE O

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP. 4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.45	0.55		
A1	0.00	0.05		
A3	0.13 REF			
b	0.12	0.22		
D	1.00	BSC		
Е	1.00	BSC		
е	0.35	BSC		
L	0.25 0.35			
L1	0.30	0.40		

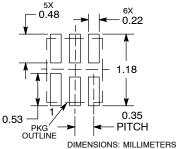




X = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

RECOMMENDED **SOLDERING FOOTPRINT***



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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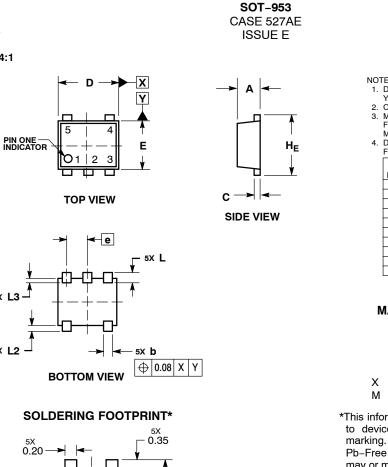
5X L3

5X L2

PACKAGE OUTLINE

0.35 PITCH





DATE 02 AUG 2011

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	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.34	0.37	0.40	
b	0.10	0.15	0.20	
С	0.07	0.12	0.17	
D	0.95	1.00	1.05	
E	0.75	0.80	0.85	
е	0.35 BSC			
ΗE	0.95	1.00	1.05	
L	0.175 REF			
L2	0.05	0.10	0.15	
L3			0.15	

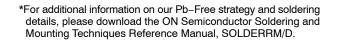
GENERIC **MARKING DIAGRAM***

= Specific Device Code

= Month Code

*This information is generic. Please refer to device data sheet for actual part

Pb-Free indicator, "G" or microdot " .", may or may not be present.



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